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2N4403 / MMBT4403 PNP General-Purpose Amplifier

Description

This device is designed for use as a general-purpose amplifier and switch for collector currents to 500 mA.

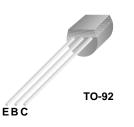


Figure 1. 2N4403 Device Package

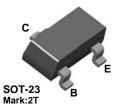


Figure 2. MMBT4403 Device Package

Part Number	Marking	Package	Packing Method
2N4403BU	2N4403	TO-92 3L	Bulk
2N4403TF	2N4403	TO-92 3L	Tape and Reel
2N4403TFR	2N4403	TO-92 3L	Tape and Reel
2N4403TA	2N4403	TO-92 3L	Ammo
2N4403TAR	2N4403	TO-92 3L	Ammo
MMBT4403	2T	SOT-23 3L	Tape and Reel

Ordering Information

Absolute Maximum Ratings^{(1),(2)}

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{CEO}	Collector-Emitter Voltage	-40	V
V _{CBO}	Collector-Base Voltage	-40	V
V _{EBO}	Emitter-Base Voltage	-5.0	V
Ι _C	Collector Current - Continuous	-600	mA
T _{J,} T _{STG}	Operating and Storage Junction Temperature Range	-55 to +150	°C

Notes:

- 1. These ratings are based on a maximum junction temperature of 150°C.
- 2. These are steady-state limits. ON Semiconductor should be consulted on applications involving pulsed or lowduty cycle operations.

Thermal Characteristics

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Max.		Unit
		2N4403 ⁽³⁾	MMBT4403 ⁽⁴⁾	Onit
PD	Total Device Dissipation	625	350	mW
	Derate Above 25°C	5.0	2.8	mW/°C
R _{θJC}	Thermal Resistance, Junction to Case	83.3		°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W

Notes:

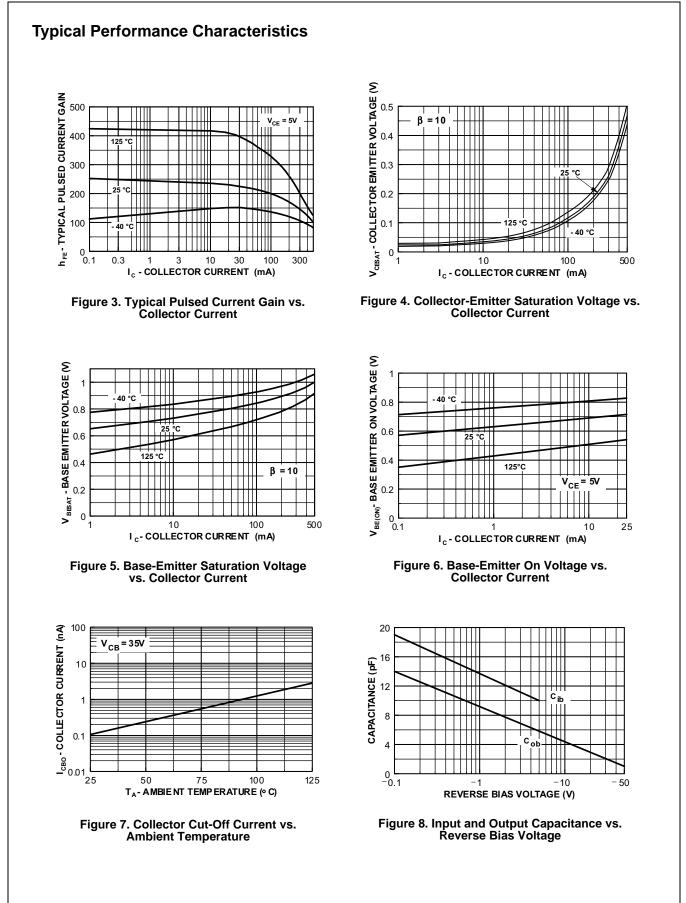
3. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

4. Device mounted on FR-4 PCB 1.6 inch x 1.6 inch x 0.06 inch.

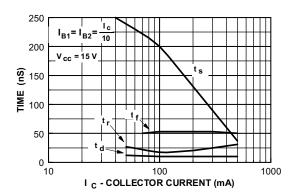
Symbol	Parameter	Conditions	Min.	Max.	Unit
Off Charact	eristics	1			
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage ⁽⁵⁾	I _C = -1.0 mA, I _B = 0	-40		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = -0.1 {\rm mA}, I_{\rm E} = 0$	-40		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = -0.1 mA, I _C = 0	-5.0		V
I _{BL}	Base Cut-Off Current	V_{CE} = -35 V, V_{EB} = -0.4 V		-0.1	μA
I _{CEX}	Collector Cut-Off Current	V_{CE} = -35 V, V_{EB} = -0.4 V		-0.1	μΑ
On Charact	eristics	· · ·			
		$I_{\rm C}$ = -0.1 mA, $V_{\rm CE}$ = -1.0 V	30		
	DC Current Gain	$I_{\rm C}$ = -1.0 mA, $V_{\rm CE}$ = -1.0 V	60		
h _{FE}		I _C = -10 mA, V _{CE} = -1.0 V	100		
		$I_{\rm C}$ = -150 mA, $V_{\rm CE}$ = -2.0 V ⁽⁵⁾	100	300	
		$I_{\rm C}$ = -500 mA, $V_{\rm CE}$ = -2.0 V ⁽⁵⁾	20		
V _{CE} (sat)	Collector-Emitter Saturation Voltage ⁽⁵⁾	I _C = -150 mA, I _B = -15 mA		-0.40	- V
		I _C = -500 mA, I _B = -50 mA		-0.75	
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_{\rm C}$ = -150 mA, $I_{\rm B}$ = -15 mA ⁽⁵⁾	-0.75	-0.95	- v
		I _C = -500 mA, I _B = -50 mA		-1.30	
Small Signa	al Characteristics				
f _T	Current Gain - Bandwidth Product	$I_{C} = -20 \text{ mA}, V_{CE} = -10 \text{ V},$ f = 100 MHz	200		MHz
C _{cb}	Collector-Base Capacitance	$V_{CB} = -10 \text{ V}, I_E = 0,$ f = 140 kHz		8.5	pF
C _{eb}	Emitter-Base Capacitance	$V_{BE} = -0.5 \text{ V}, I_{C} = 0,$ f = 140 kHz		30	pF
h _{ie}	Input Impedance	$I_{\rm C}$ = -1.0 mA, $V_{\rm CE}$ = -10 V, f = 1.0 kHz	1.5	15.0	kΩ
h _{re}	Voltage Feedback Ratio	I _C = -1.0 mA, V _{CE} = -10 V, f = 1.0 kHz	0.1	8.0	x10 ⁻⁴
h _{fe}	Small-Signal Current Gain	$I_{C} = -1.0 \text{ mA}, V_{CE} = -10 \text{ V},$ f = 1.0 kHz	60	500	
h _{oe}	Output Admittance	$I_{C} = -1.0 \text{ mA}, V_{CE} = -10 \text{ V},$ f = 1.0 kHz	1	100	μmhos
Switching (Characteristics				
t _d	Delay Time	V _{CC} = -30 V, I _C = -150 mA,		15	ns
t _r	Rise Time	I _{B1} = -15 mA		20	ns
t _s	Storage Time	V _{CC} = -30 V, I _C = -150 mA,		225	ns
t _f	Fall Time	$I_{B1} = I_{B2} = -15 \text{ mA}$		30	ns

Note:

5. Pulse test: pulse width \leq 300 µs, duty cycle \leq 2.0%.



Typical Performance Characteristics (Continued)





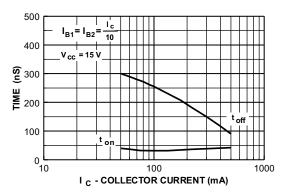
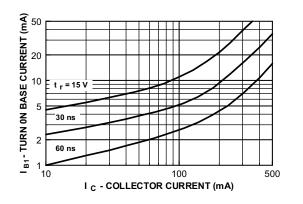
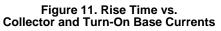


Figure 10. Turn-On and Turn-Off Times vs. Collector Current





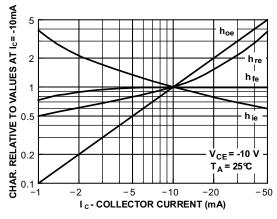


Figure 13. Common Emitter Characteristics

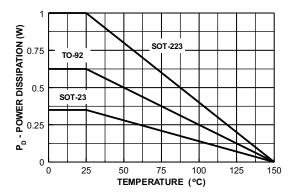
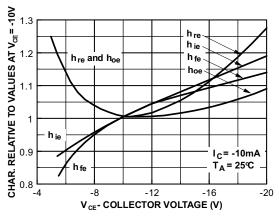


Figure 12. Power Dissipation vs. Ambient Temperature





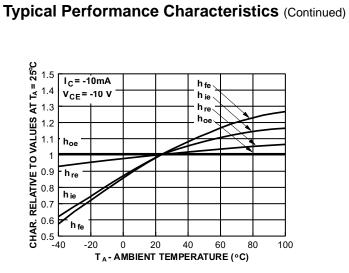
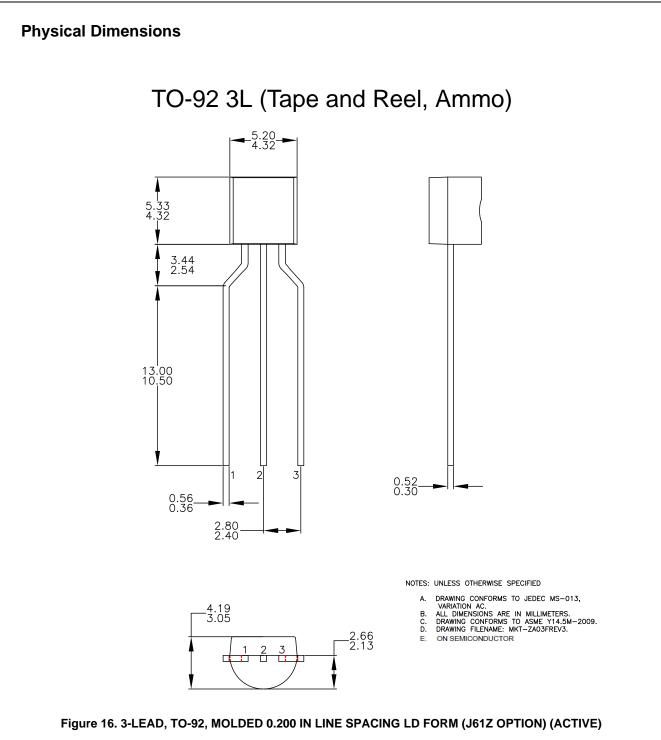
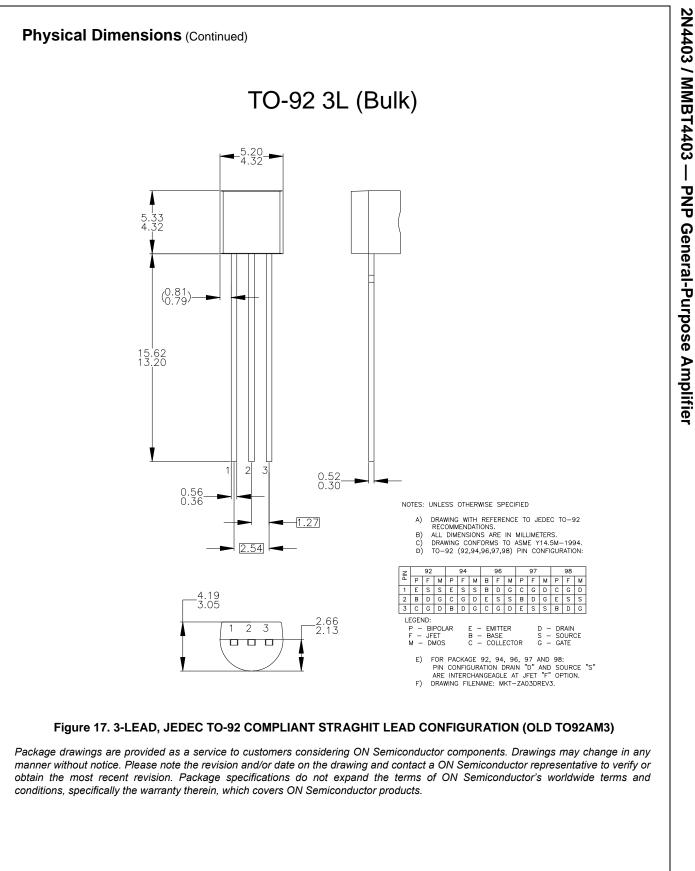
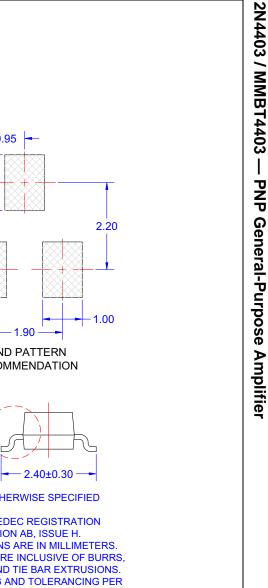


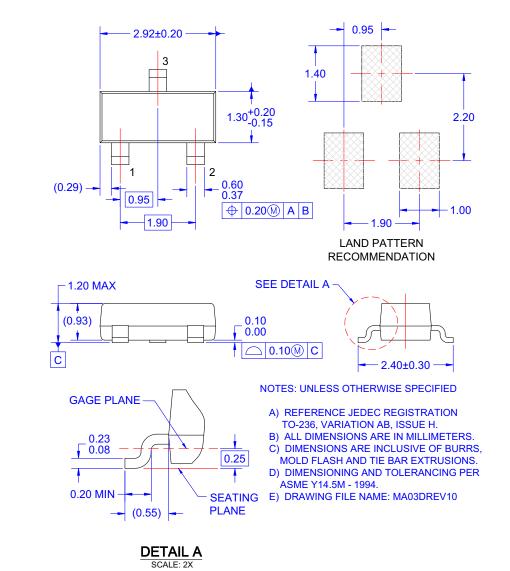
Figure 15. Common Emitter Characteristics



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SOT-23 3L

Figure 18. 3-LEAD, SOT23, JEDEC TO-236, LOW PROFILE (ACTIVE)

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